

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	60	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	Ι _D	5.5 4.4	A
	t<10s	T _A = 25°C T _A = 70°C	Ι _D	7.0 5.5	A
Maximum Continuous Body Diode Forward Current (Note 6)			Is	2.5	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	30	А
Avalanche Current (Note 7) L = 0.1mH			I _{AR}	14.2	А
Repetitive Avalanche Energy (Note 7) L = 0.1mH			E _{AR}	10	mJ

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Units	
Total Dower Dissinction (Note 5)	T _A = 25°C	D	1.5	W	
Total Power Dissipation (Note 5)	T _A = 70°C	PD	1	vv	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	80	°C/W	
	t<10s	$R_{ heta JA}$	48		
Total Power Dissipation (Note 6)	T _A = 25°C	D	2.0	W	
	$T_A = 70^{\circ}C$	PD	1.3		
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	5	61	°C/W	
	t<10s	$R_{ heta JA}$	37		
Thermal Resistance, Junction to Case		$R_{\theta JC}$	6.4		
Operating and Storage Temperature Range		TJ, TSTG	-55 to 150	°C	

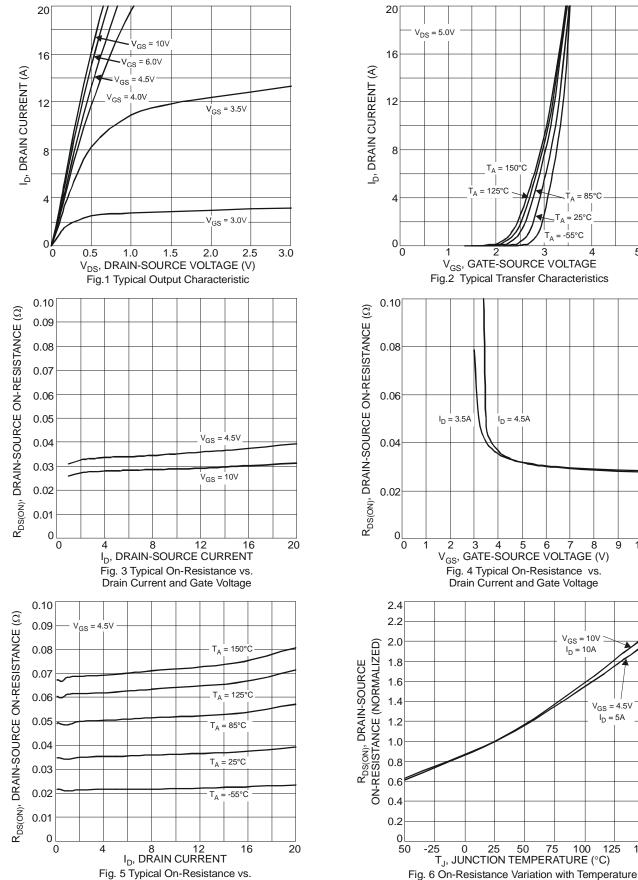
Electrical Characteristics T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Symbol	IAIIII	тур	INIAX	Unit	Test condition	
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_{D} = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}			100	nA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)				•			
Gate Threshold Voltage	V _{GS(th)}	1	_	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	30	40		$V_{GS} = 10V, I_D = 4.5A$	
Static Dialit-Source Off-Resistance	R _{DS (ON)}	_	35	55	mΩ	$V_{GS} = 4.5V, I_D = 3.5A$	
Forward Transfer Admittance	Y _{fs}	_	4.5	_	S	$V_{DS} = 10V, I_D = 4.3A$	
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	_	1287	_	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz	
Output Capacitance	C _{oss}	_	57	_			
Reverse Transfer Capacitance	Crss	_	44	_			
Gate Resistance	R _G	_	1.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	22.4	_			
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	10.4	_	nC	V _{DS} = 30V, I _D = 4.3A	
Gate-Source Charge	Q _{gs}	_	4.9	_	nc		
Gate-Drain Charge	Q _{gd}	_	3.0	_			
Turn-On Delay Time	t _{D(on)}	_	6.6	_	nS	$V_{GS} = 10V, V_{DD} = 30V, R_G = 6\Omega,$ $I_D = 4.3A$	
Turn-On Rise Time	tr		8.1	_			
Turn-Off Delay Time	t _{D(off)}		20.1	_	115		
Turn-Off Fall Time	t _f		4.0	_			
Body Diode Reverse Recovery Time	t _{rr}		18	_	nS	I _S = 4.3A, dl/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q _{rr}		11.9	—	nC	I _S = 4.3A, dl/dt = 100A/µs	

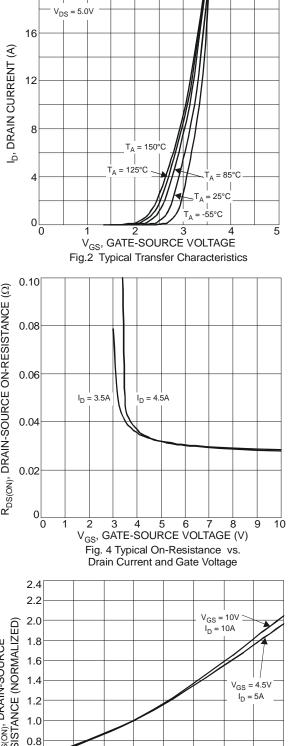
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. 7. I_{AR} and E_{AR} rating are based on low frequency and duty cycles to keep $T_J = 25^{\circ}$ C Notes:

8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.





Drain Current and Temperature

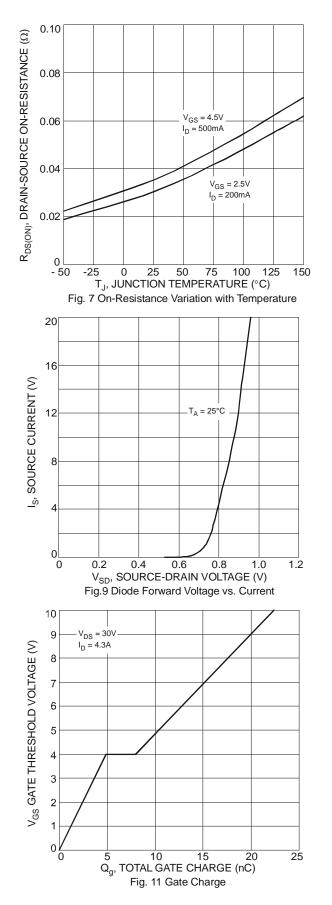


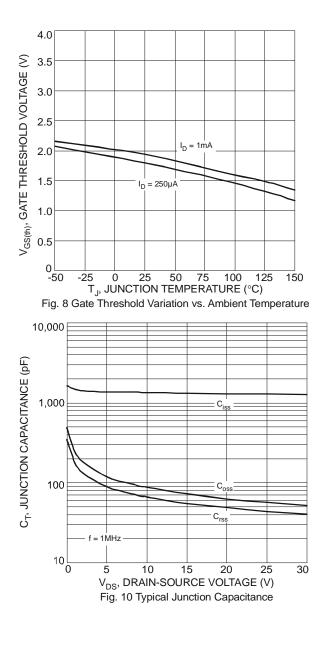
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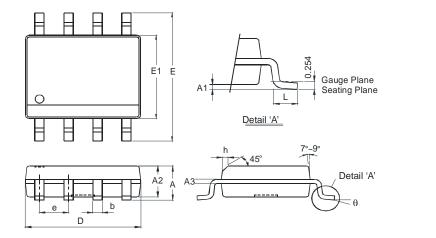






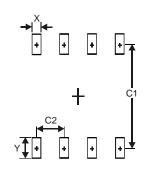


Package Outline Dimensions



SO-8				
Dim	Min	Max		
Α	-	1.75		
A1	0.10	0.20		
A2	1.30	1.50		
A3	0.15	0.25		
b	0.3	0.5		
D	4.85	4.95		
ш	5.90	6.10		
E1	3.85	3.95		
е	1.27 Typ			
h	-	0.35		
Г	0.62	0.82		
θ	0°	8°		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27



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